

## Low voltage PNP power transistor

### Application

- General purpose switching and amplifier

### Description

The device is manufactured in planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The NPN type is TIP29C.

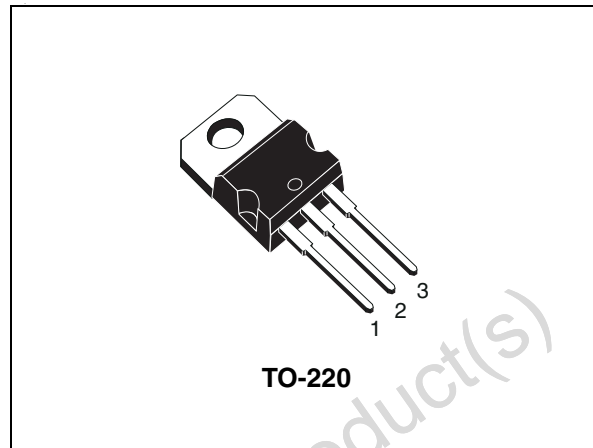


Figure 1. Internal schematic diagram

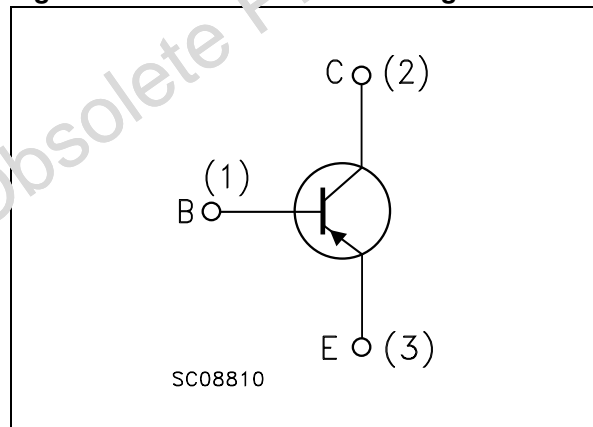


Table 1. Device summary

Order code	Marking	Package	Packaging
TIP30C	TIP30C	TO-220	Tube

# 1 Absolute maximum ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base voltage ( $I_E = 0$ )	-100	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )	-100	V
$V_{EBO}$	Emitte-base voltage ( $I_C = 0$ )	-5	V
$I_C$	Collector current	-1	A
$I_{CM}$	Collector peak current ( $t_P < 5\text{ms}$ )	-3	A
$I_B$	Base current	-0.4	A
$P_{TOT}$	Total dissipation at $T_{case} = 25^\circ\text{C}$ $T_{amb} = 25^\circ\text{C}$	30	W
		2	W
$T_{stg}$	Storage temperature	-65 to 150	$^\circ\text{C}$
$T_J$	Max. operating junction temperature	150	$^\circ\text{C}$

## 2 Electrical characteristics

( $T_{\text{case}} = 25^{\circ}\text{C}$ ; unless otherwise specified)

**Table 3. Electrical characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{\text{CEO}}$	Collector cut-off current ( $I_{\text{B}} = 0$ )	$V_{\text{CE}} = -60 \text{ V}$			-0.3	mA
$I_{\text{CES}}$	Collector cut-off current ( $V_{\text{BE}} = 0$ )	$V_{\text{CE}} = -100 \text{ V}$			-0.2	mA
$I_{\text{EBO}}$	Emitter cut-off current ( $I_{\text{C}} = 0$ )	$V_{\text{EB}} = -5 \text{ V}$			-1	mA
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ( $I_{\text{B}} = 0$ )	$I_{\text{C}} = -30 \text{ mA}$	-100			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = -1 \text{ A}$ $I_{\text{B}} = -125 \text{ mA}$			-0.7	V
$V_{\text{BE(on)}}^{(1)}$	Base-emitter voltage	$I_{\text{C}} = -1 \text{ A}$ $V_{\text{CE}} = -4 \text{ V}$			-1.3	V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = -200 \text{ mA}$ $V_{\text{CE}} = -4 \text{ V}$ $I_{\text{C}} = -1 \text{ A}$ $V_{\text{CE}} = -4 \text{ V}$	40 15		75	

1. Pulsed duration = 300 ms, duty cycle  $\geq 1.5\%$ .

## 2.1 Typical characteristic (curves)

Figure 2. DC current gain

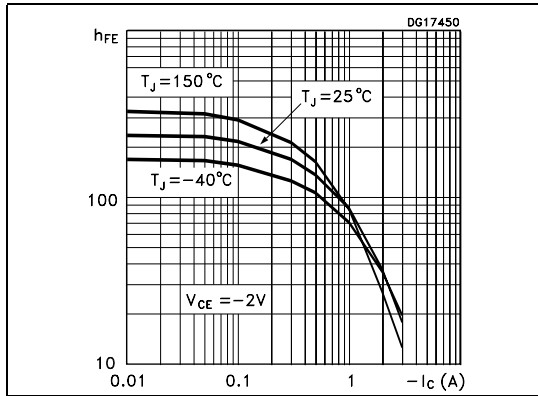


Figure 3. DC current gain

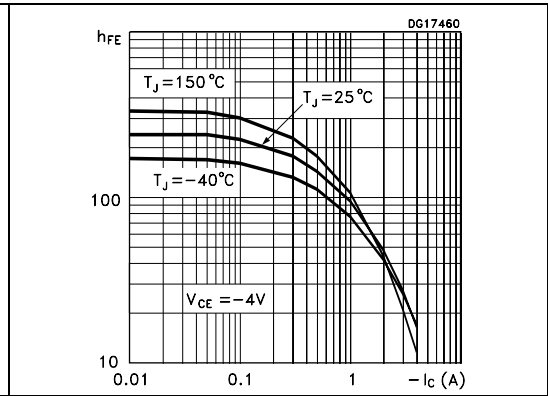


Figure 4. Collector-emitter saturation voltage

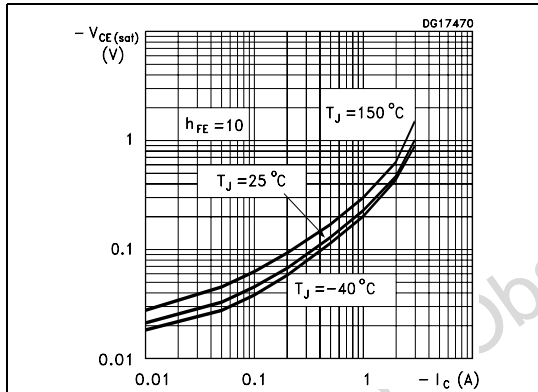


Figure 5. Base-emitter saturation voltage

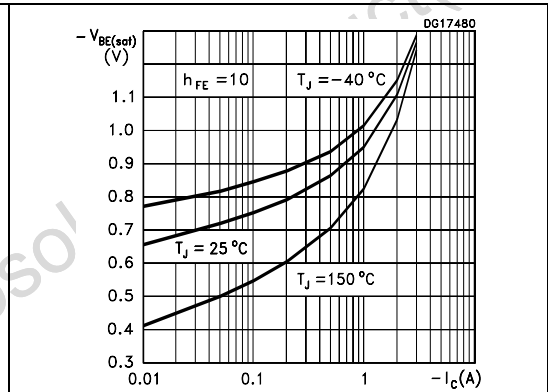


Figure 6. Resistive load switching time

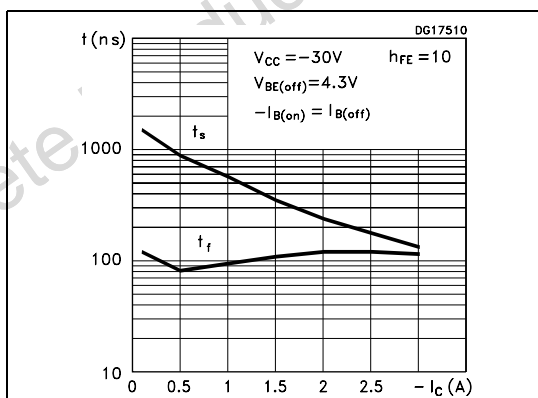


Figure 7. Resistive load switching time

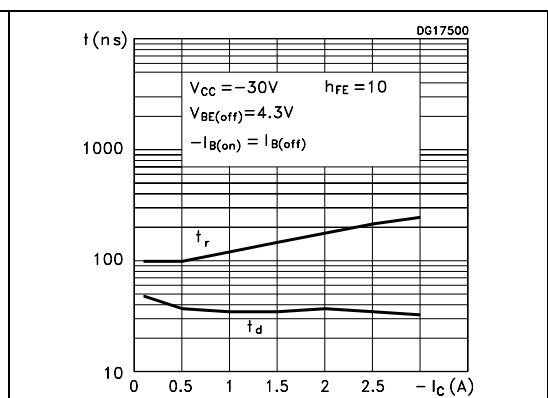
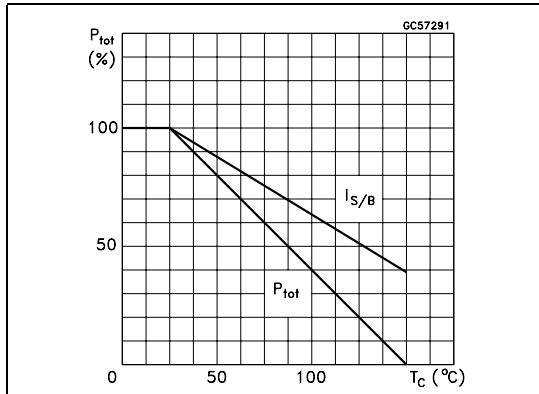
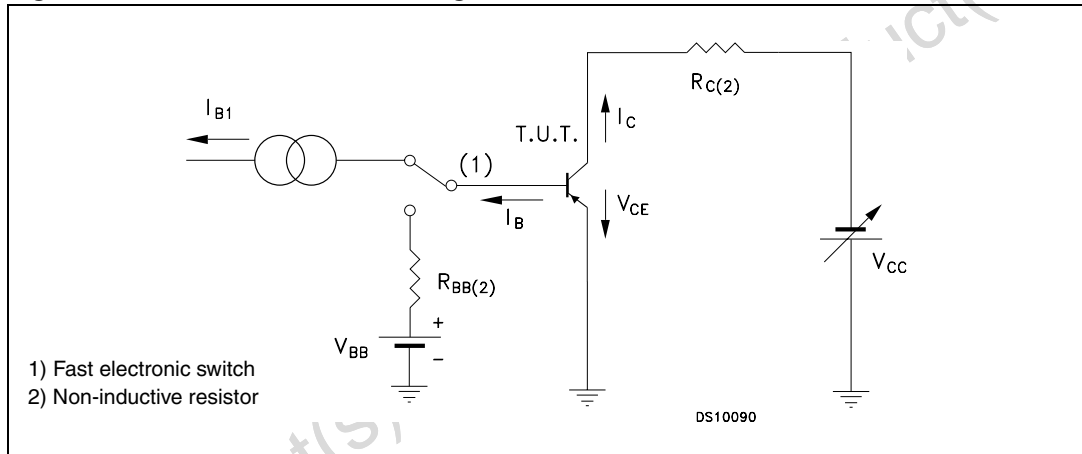


Figure 8. Derating curve



## 2.2 Test circuits

Figure 9. Resistive load switching test circuit



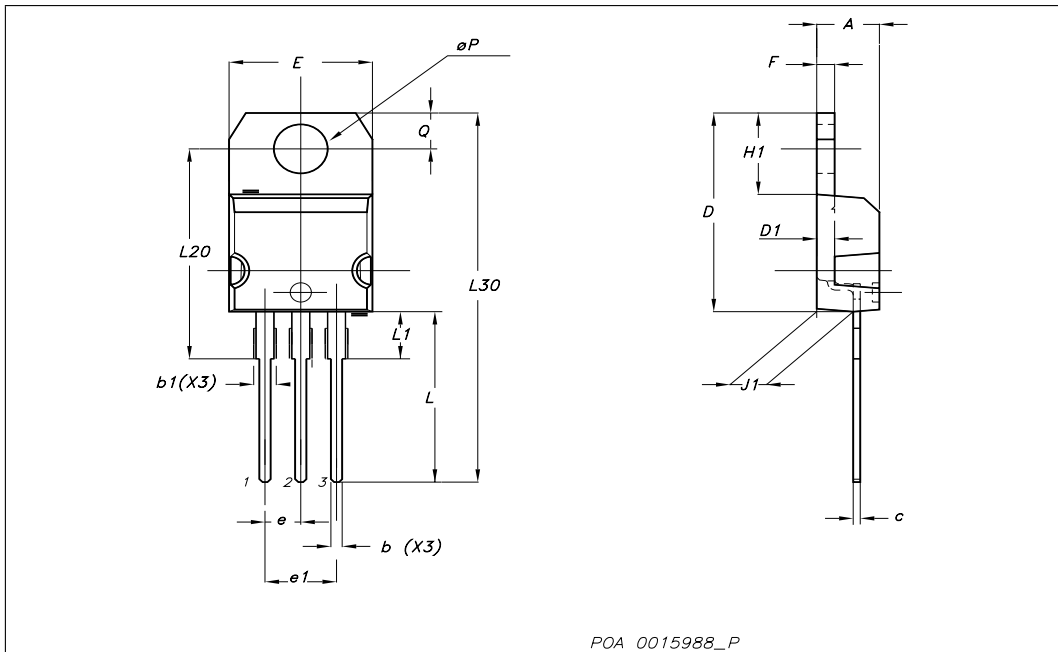
### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com)

Obsolete Product(s) - Obsolete Product(s)

TO-220 mechanical data

Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.49		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
∅P	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



Obsole

## 4 Revision history

Table 4. Document revision history

Date	Revision	Changes
11-Oct-2007	1	Initial release

Obsolete Product(s) - Obsolete Product(s)



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